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Understanding <u>Embedded - FPGAs (Field Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	72
Number of Logic Elements/Cells	576
Total RAM Bits	12288
Number of I/O	120
Number of Gates	56000
Voltage - Supply	2.375V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 70°C (TA)
Package / Case	208-BFQFP
Supplier Device Package	208-PQFP (28x28)
Purchase URL	https://www.e-xfl.com/product-detail/intel/ep1k10qc208-3

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Figure 3. ACEX 1K EAB in Dual-Port RAM Mode

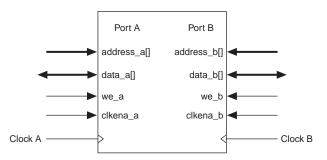
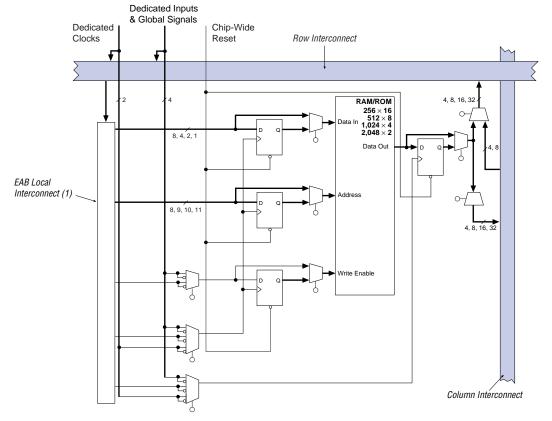


Figure 4. ACEX 1K Device in Single-Port RAM Mode



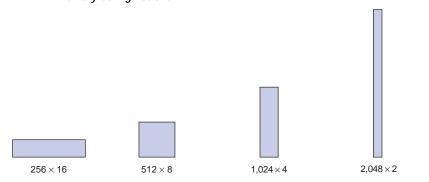
Note

(1) EP1K10, EP1K30, and EP1K50 devices have 88 EAB local interconnect channels; EP1K100 devices have 104 EAB local interconnect channels.

EABs can be used to implement synchronous RAM, which is easier to use than asynchronous RAM. A circuit using asynchronous RAM must generate the RAM write enable signal, while ensuring that its data and address signals meet setup and hold time specifications relative to the write enable signal. In contrast, the EAB's synchronous RAM generates its own write enable signal and is self-timed with respect to the input or write clock. A circuit using the EAB's self-timed RAM must only meet the setup and hold time specifications of the global clock.

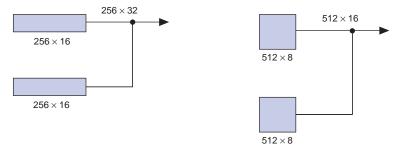
When used as RAM, each EAB can be configured in any of the following sizes: 256×16 ; 512×8 ; $1,024 \times 4$; or $2,048 \times 2$. Figure 5 shows the ACEX 1K EAB memory configurations.

Figure 5. ACEX 1K EAB Memory Configurations



Larger blocks of RAM are created by combining multiple EABs. For example, two 256×16 RAM blocks can be combined to form a 256×32 block, and two 512×8 RAM blocks can be combined to form a 512×16 block. Figure 6 shows examples of multiple EAB combination.

Figure 6. Examples of Combining ACEX 1K EABs



Clearable Counter Mode

The clearable counter mode is similar to the up/down counter mode, but it supports a synchronous clear instead of the up/down control. The clear function is substituted for the cascade-in signal in the up/down counter mode. Two 3-input LUTs are used; one generates the counter data, and the other generates the fast carry bit. Synchronous loading is provided by a 2-to-1 multiplexer. The output of this multiplexer is AND ed with a synchronous clear signal.

Internal Tri-State Emulation

Internal tri-state emulation provides internal tri-states without the limitations of a physical tri-state bus. In a physical tri-state bus, the tri-state buffers' output enable (OE) signals select which signal drives the bus. However, if multiple OE signals are active, contending signals can be driven onto the bus. Conversely, if no OE signals are active, the bus will float. Internal tri-state emulation resolves contending tri-state buffers to a low value and floating buses to a high value, thereby eliminating these problems. The Altera software automatically implements tri-state bus functionality with a multiplexer.

Clear & Preset Logic Control

Logic for the programmable register's clear and preset functions is controlled by the DATA3, LABCTRL1, and LABCTRL2 inputs to the LE. The clear and preset control structure of the LE asynchronously loads signals into a register. Either LABCTRL1 or LABCTRL2 can control the asynchronous clear. Alternatively, the register can be set up so that LABCTRL1 implements an asynchronous load. The data to be loaded is driven to DATA3; when LABCTRL1 is asserted, DATA3 is loaded into the register.

During compilation, the compiler automatically selects the best control signal implementation. Because the clear and preset functions are active-low, the Compiler automatically assigns a logic high to an unused clear or preset.

The clear and preset logic is implemented in one of the following six modes chosen during design entry:

- Asynchronous clear
- Asynchronous preset
- Asynchronous clear and preset
- Asynchronous load with clear
- Asynchronous load with preset
- Asynchronous load without clear or preset

FastTrack Interconnect Routing Structure

In the ACEX 1K architecture, connections between LEs, EABs, and device I/O pins are provided by the FastTrack Interconnect routing structure, which is a series of continuous horizontal and vertical routing channels that traverse the device. This global routing structure provides predictable performance, even in complex designs. In contrast, the segmented routing in FPGAs requires switch matrices to connect a variable number of routing paths, increasing the delays between logic resources and reducing performance.

The FastTrack Interconnect routing structure consists of row and column interconnect channels that span the entire device. Each row of LABs is served by a dedicated row interconnect. The row interconnect can drive I/O pins and feed other LABs in the row. The column interconnect routes signals between rows and can drive I/O pins.

Row channels drive into the LAB or EAB local interconnect. The row signal is buffered at every LAB or EAB to reduce the effect of fan-out on delay. A row channel can be driven by an LE or by one of three column channels. These four signals feed dual 4-to-1 multiplexers that connect to two specific row channels. These multiplexers, which are connected to each LE, allow column channels to drive row channels even when all eight LEs in a LAB drive the row interconnect.

Each column of LABs or EABs is served by a dedicated column interconnect. The column interconnect that serves the EABs has twice as many channels as other column interconnects. The column interconnect can then drive I/O pins or another row's interconnect to route the signals to other LABs or EABs in the device. A signal from the column interconnect, which can be either the output of a LE or an input from an I/O pin, must be routed to the row interconnect before it can enter a LAB or EAB. Each row channel that is driven by an IOE or EAB can drive one specific column channel.

Access to row and column channels can be switched between LEs in adjacent pairs of LABs. For example, a LE in one LAB can drive the row and column channels normally driven by a particular LE in the adjacent LAB in the same row, and vice versa. This flexibility enables routing resources to be used more efficiently. Figure 13 shows the ACEX 1K LAB.

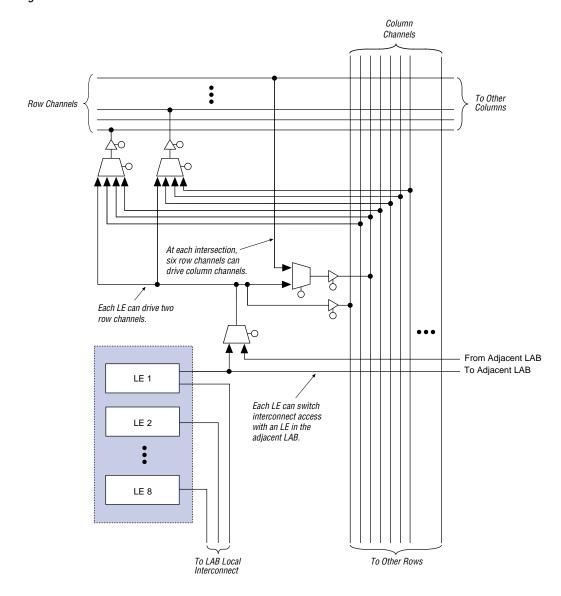


Figure 13. ACEX 1K LAB Connections to Row & Column Interconnect

For improved routing, the row interconnect consists of a combination of full-length and half-length channels. The full-length channels connect to all LABs in a row; the half-length channels connect to the LABs in half of the row. The EAB can be driven by the half-length channels in the left half of the row and by the full-length channels. The EAB drives out to the full-length channels. In addition to providing a predictable, row-wide interconnect, this architecture provides increased routing resources. Two neighboring LABs can be connected using a half-row channel, thereby saving the other half of the channel for the other half of the row.

Table 6 summarizes the FastTrack Interconnect routing structure resources available in each ACEX 1K device.

Table 6. ACEX 1K FastTrack Interconnect Resources									
Device Rows Channels per Row Columns Channels Columns									
EP1K10	3	144	24	24					
EP1K30	6	216	36	24					
EP1K50	10	216	36	24					
EP1K100	12	312	52	24					

In addition to general-purpose I/O pins, ACEX 1K devices have six dedicated input pins that provide low-skew signal distribution across the device. These six inputs can be used for global clock, clear, preset, and peripheral output-enable and clock-enable control signals. These signals are available as control signals for all LABs and IOEs in the device. The dedicated inputs can also be used as general-purpose data inputs because they can feed the local interconnect of each LAB in the device.

Figure 14 shows the interconnection of adjacent LABs and EABs, with row, column, and local interconnects, as well as the associated cascade and carry chains. Each LAB is labeled according to its location: a letter represents the row and a number represents the column. For example, LAB B3 is in row B, column 3.

See Figure 17 for details. I/O Element (IOE) IOF IIOF IOE IOE IOE IOE Row LAB LAB See Figure 16 I AR Interconnect Α1 A2 АЗ for details. Column ►To LAB A5 Interconnect ►To LAB A4 IOE IOE LAB LAB I AR Cascade & B1 R2 В3 Carry Chains To LAB B5 ►To LAB B4 IOE IOE IOE

Figure 14. ACEX 1K Interconnect Resources

I/O Element

An IOE contains a bidirectional I/O buffer and a register that can be used either as an input register for external data that requires a fast setup time or as an output register for data that requires fast clock-to-output performance. In some cases, using an LE register for an input register will result in a faster setup time than using an IOE register. IOEs can be used as input, output, or bidirectional pins. The compiler uses the programmable inversion option to invert signals from the row and column interconnect automatically where appropriate. For bidirectional registered I/O implementation, the output register should be in the IOE and the data input and output enable registers should be LE registers placed adjacent to the bidirectional pin. Figure 15 shows the bidirectional I/O registers.



For more information, search for "SameFrame" in MAX+PLUS II Help.

Table 10. ACEX 1K SameFrame Pin-Out Support							
Device	256-Pin FineLine BGA	484-Pin FineLine BGA					
EP1K10	✓	(1)					
EP1K30	✓	(1)					
EP1K50	✓	✓					
EP1K100	✓	✓					

Note:

 This option is supported with a 256-pin FineLine BGA package and SameFrame migration.

ClockLock & ClockBoost Features

To support high-speed designs, -1 and -2 speed grade ACEX 1K devices offer ClockLock and ClockBoost circuitry containing a phase-locked loop (PLL) that is used to increase design speed and reduce resource usage. The ClockLock circuitry uses a synchronizing PLL that reduces the clock delay and skew within a device. This reduction minimizes clock-to-output and setup times while maintaining zero hold times. The ClockBoost circuitry, which provides a clock multiplier, allows the designer to enhance device area efficiency by sharing resources within the device. The ClockBoost feature allows the designer to distribute a low-speed clock and multiply that clock on-device. Combined, the ClockLock and ClockBoost features provide significant improvements in system performance and bandwidth.

The ClockLock and ClockBoost features in ACEX 1K devices are enabled through the Altera software. External devices are not required to use these features. The output of the ClockLock and ClockBoost circuits is not available at any of the device pins.

The ClockLock and ClockBoost circuitry lock onto the rising edge of the incoming clock. The circuit output can drive the clock inputs of registers only; the generated clock cannot be gated or inverted.

The dedicated clock pin (GCLK1) supplies the clock to the ClockLock and ClockBoost circuitry. When the dedicated clock pin is driving the ClockLock or ClockBoost circuitry, it cannot drive elsewhere in the device.

PCI Pull-Up Clamping Diode Option

ACEX 1K devices have a pull-up clamping diode on every I/O, dedicated input, and dedicated clock pin. PCI clamping diodes clamp the signal to the $V_{\rm CCIO}$ value and are required for 3.3-V PCI compliance. Clamping diodes can also be used to limit overshoot in other systems.

Clamping diodes are controlled on a pin-by-pin basis. When $V_{\rm CCIO}$ is 3.3 V, a pin that has the clamping diode option turned on can be driven by a 2.5-V or 3.3-V signal, but not a 5.0-V signal. When $V_{\rm CCIO}$ is 2.5 V, a pin that has the clamping diode option turned on can be driven by a 2.5-V signal, but not a 3.3-V or 5.0-V signal. Additionally, a clamping diode can be activated for a subset of pins, which allows a device to bridge between a 3.3-V PCI bus and a 5.0-V device.

Slew-Rate Control

The output buffer in each IOE has an adjustable output slew rate that can be configured for low-noise or high-speed performance. A slower slew rate reduces system noise and adds a maximum delay of 4.3 ns. The fast slew rate should be used for speed-critical outputs in systems that are adequately protected against noise. Designers can specify the slew rate pin-by-pin or assign a default slew rate to all pins on a device-wide basis. The slow slew rate setting affects only the falling edge of the output.

Open-Drain Output Option

ACEX 1K devices provide an optional open-drain output (electrically equivalent to open-collector output) for each I/O pin. This open-drain output enables the device to provide system-level control signals (e.g., interrupt and write enable signals) that can be asserted by any of several devices. It can also provide an additional wired- $\[OR]$ plane.

MultiVolt I/O Interface

The ACEX 1K device architecture supports the MultiVolt I/O interface feature, which allows ACEX 1K devices in all packages to interface with systems of differing supply voltages. These devices have one set of V_{CC} pins for internal operation and input buffers (VCCINT), and another set for I/O output drivers (VCCIO).

Figure 22 shows the required relationship between V_{CCIO} and V_{CCINT} to satisfy 3.3-V PCI compliance.

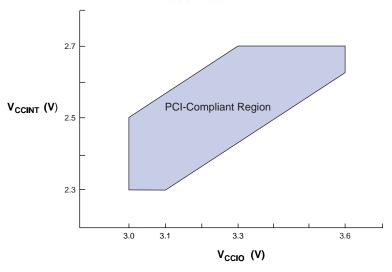


Figure 22. Relationship between V_{CCIO} & V_{CCINT} for 3.3-V PCI Compliance

Figure 23 shows the typical output drive characteristics of ACEX 1K devices with 3.3-V and 2.5-V $V_{\rm CCIO}$. The output driver is compliant to the 3.3-V *PCI Local Bus Specification, Revision 2.2* (when VCCIO pins are connected to 3.3 V). ACEX 1K devices with a -1 speed grade also comply with the drive strength requirements of the *PCI Local Bus Specification, Revision 2.2* (when VCCINT pins are powered with a minimum supply of 2.375 V, and VCCIO pins are connected to 3.3 V). Therefore, these devices can be used in open 5.0-V PCI systems.

Tables 27 through 29 describe the ACEX 1K external timing parameters and their symbols.

Table 27. Exte		
Symbol	Parameter	Conditions
t _{DRR}	Register-to-register delay via four LEs, three row interconnects, and four local interconnects	(2)

Table 28. External Timing Parameters							
Symbol	Parameter	Conditions					
t _{INSU}	Setup time with global clock at IOE register	(3)					
t _{INH}	Hold time with global clock at IOE register	(3)					
tоитсо	Clock-to-output delay with global clock at IOE register	(3)					
t _{PCISU}	Setup time with global clock for registers used in PCI designs	(3), (4)					
t _{PCIH}	Hold time with global clock for registers used in PCI designs	(3), (4)					
t _{PCICO}	Clock-to-output delay with global clock for registers used in PCI designs	(3), (4)					

Table 29. External Bidirectional Timing Parameters Note (3)							
Symbol	Parameter	Conditions					
t _{INSUBIDIR}	Setup time for bidirectional pins with global clock at same-row or same-column LE register						
t _{INHBIDIR}	Hold time for bidirectional pins with global clock at same-row or same-column LE register						
t _{OUTCOBIDIR}	Clock-to-output delay for bidirectional pins with global clock at IOE register	CI = 35 pF					
t _{XZBIDIR}	Synchronous IOE output buffer disable delay	CI = 35 pF					
t _{ZXBIDIR}	Synchronous IOE output buffer enable delay, slow slew rate = off	CI = 35 pF					

Notes to tables:

- (1) External reference timing parameters are factory-tested, worst-case values specified by Altera. A representative subset of signal paths is tested to approximate typical device applications.
- (2) Contact Altera Applications for test circuit specifications and test conditions.
- (3) These timing parameters are sample-tested only.
- (4) This parameter is measured with the measurement and test conditions, including load, specified in the *PCI Local Bus Specification*, *Revision 2.2.*

Tables 30 through 36 show EP1K10 device internal and external timing parameters.

Table 30. EP1K10 Device LE Timing Microparameters Note (1)							
Symbol		Unit					
	-	1	-	2	-3		
	Min	Max	Min	Max	Min	Max	
t_{LUT}		0.7		0.8		1.1	ns
t_{CLUT}		0.5		0.6		0.8	ns
t _{RLUT}		0.6		0.7		1.0	ns
t _{PACKED}		0.4		0.4		0.5	ns
t_{EN}		0.9		1.0		1.3	ns
t_{CICO}		0.1		0.1		0.2	ns
t _{CGEN}		0.4		0.5		0.7	ns
t _{CGENR}		0.1		0.1		0.2	ns
t _{CASC}		0.7		0.9		1.1	ns
t_{C}		1.1		1.3		1.7	ns
$t_{\rm CO}$		0.5		0.7		0.9	ns
t _{COMB}		0.4		0.5		0.7	ns
t _{SU}	0.7		0.8		1.0		ns
t _H	0.9		1.0		1.1		ns
t _{PRE}		0.8		1.0		1.4	ns
t _{CLR}		0.9		1.0		1.4	ns
t _{CH}	2.0		2.5		2.5		ns
t_{CL}	2.0		2.5		2.5		ns

Symbol		Speed Grade							
	_	1	-2		_	3			
	Min	Max	Min	Max	Min	Max			
t _{EABDATA1}		1.7		2.0		2.3	ns		
t _{EABDATA1}		0.6		0.7		0.8	ns		
t _{EABWE1}		1.1		1.3		1.4	ns		
t _{EABWE2}		0.4		0.4		0.5	ns		
t _{EABRE1}		0.8		0.9		1.0	ns		
t _{EABRE2}		0.4		0.4		0.5	ns		
t _{EABCLK}		0.0		0.0		0.0	ns		
t _{EABCO}		0.3		0.3		0.4	ns		
t _{EABBYPASS}		0.5		0.6		0.7	ns		
t _{EABSU}	0.9		1.0		1.2		ns		
t _{EABH}	0.4		0.4		0.5		ns		
t _{EABCLR}	0.3		0.3		0.3		ns		
t_{AA}		3.2		3.8		4.4	ns		
t_{WP}	2.5		2.9		3.3		ns		
t_{RP}	0.9		1.1		1.2		ns		
t _{WDSU}	0.9		1.0		1.1		ns		
t_{WDH}	0.1		0.1		0.1		ns		
t _{WASU}	1.7		2.0		2.3		ns		
t _{WAH}	1.8		2.1		2.4		ns		
t _{RASU}	3.1		3.7		4.2		ns		
t _{RAH}	0.2		0.2		0.2		ns		
t_{WO}		2.5		2.9		3.3	ns		
t_{DD}		2.5		2.9		3.3	ns		
t _{EABOUT}		0.5		0.6		0.7	ns		
t _{EABCH}	1.5		2.0		2.3		ns		
t _{EABCL}	2.5		2.9		3.3		ns		

Symbol			Speed	Grade			Unit
	-	1	-	2	-3		
	Min	Max	Min	Max	Min	Max	
DIN2IOE		1.8		2.4		2.9	ns
t _{DIN2LE}		1.5		1.8		2.4	ns
t _{DIN2DATA}		1.5		1.8		2.2	ns
t _{DCLK2IOE}		2.2		2.6		3.0	ns
t _{DCLK2LE}		1.5		1.8		2.4	ns
t _{SAMELAB}		0.1		0.2		0.3	ns
t _{SAMEROW}		2.0		2.4		2.7	ns
t _{SAME} COLUMN		0.7		1.0		0.8	ns
t _{DIFFROW}		2.7		3.4		3.5	ns
t _{TWOROWS}		4.7		5.8		6.2	ns
LEPERIPH		2.7		3.4		3.8	ns
LABCARRY		0.3		0.4		0.5	ns
t _{LABCASC}		0.8		0.8		1.1	ns

Table 42. EP1K30 External Timing Parameters Notes (1), (2)									
Symbol		Speed Grade							
		-1		-2		3			
	Min	Max	Min	Max	Min	Max			
t _{DRR}		8.0		9.5		12.5	ns		
t _{INSU} (3)	2.1		2.5		3.9		ns		
t _{INH} (3)	0.0		0.0		0.0		ns		
t _{оитсо} (3)	2.0	4.9	2.0	5.9	2.0	7.6	ns		
t _{INSU} (4)	1.1		1.5		-		ns		
t _{INH} (4)	0.0		0.0		-		ns		
t _{оитсо} (4)	0.5	3.9	0.5	4.9	-	-	ns		
t _{PCISU}	3.0		4.2		-		ns		
t _{PCIH}	0.0		0.0		-		ns		
t _{PCICO}	2.0	6.0	2.0	7.5	-	_	ns		

Symbol			Speed	Grade			Unit
	-	1	-2		-3		
	Min	Max	Min	Max	Min	Max	
t _{DIN2IOE}		3.1		3.7		4.6	ns
t _{DIN2LE}		1.7		2.1		2.7	ns
t _{DIN2DATA}		2.7		3.1		5.1	ns
t _{DCLK2IOE}		1.6		1.9		2.6	ns
t _{DCLK2LE}		1.7		2.1		2.7	ns
t _{SAMELAB}		0.1		0.1		0.2	ns
t _{SAMEROW}		1.5		1.7		2.4	ns
t _{SAME} COLUMN		1.0		1.3		2.1	ns
t _{DIFFROW}		2.5		3.0		4.5	ns
t _{TWOROWS}		4.0		4.7		6.9	ns
t _{LEPERIPH}		2.6		2.9		3.4	ns
t _{LABCARRY}		0.1		0.2		0.2	ns
t _{LABCASC}		0.8		1.0		1.3	ns

Table 49. EP1K50 External Timing Parameters Note (1)									
Symbol		Unit							
	-1		-2		-3				
	Min	Max	Min	Max	Min	Max			
t _{DRR}		8.0		9.5		12.5	ns		
t _{INSU} (2)	2.4		2.9		3.9		ns		
t _{INH} (2)	0.0		0.0		0.0		ns		
t _{оитсо} (2)	2.0	4.3	2.0	5.2	2.0	7.3	ns		
t _{INSU} (3)	2.4		2.9		-		ns		
t _{INH} (3)	0.0		0.0		-		ns		
t _{оитсо} (3)	0.5	3.3	0.5	4.1	-	-	ns		
t _{PCISU}	2.4		2.9		-		ns		
t _{PCIH}	0.0		0.0		-		ns		
t _{PCICO}	2.0	6.0	2.0	7.7	-	-	ns		

Tables 51 through 57 show EP1K100 device internal and external timing parameters.

Symbol	Speed Grade						Unit
	-1		-2		-3		
	Min	Max	Min	Max	Min	Max	
t_{LUT}		0.7		1.0		1.5	ns
t _{CLUT}		0.5		0.7		0.9	ns
t _{RLUT}		0.6		0.8		1.1	ns
t _{PACKED}		0.3		0.4		0.5	ns
t _{EN}		0.2		0.3		0.3	ns
t _{CICO}		0.1		0.1		0.2	ns
t _{CGEN}		0.4		0.5		0.7	ns
t _{CGENR}		0.1		0.1		0.2	ns
t _{CASC}		0.6		0.9		1.2	ns
t_C		0.8		1.0		1.4	ns
t_{CO}		0.6		0.8		1.1	ns
t _{COMB}		0.4		0.5		0.7	ns
t _{SU}	0.4		0.6		0.7		ns
t _H	0.5		0.7		0.9		ns
t _{PRE}		0.8		1.0		1.4	ns
t _{CLR}		0.8		1.0		1.4	ns
t _{CH}	1.5		2.0		2.5		ns
t_{CL}	1.5		2.0		2.5	i i	ns

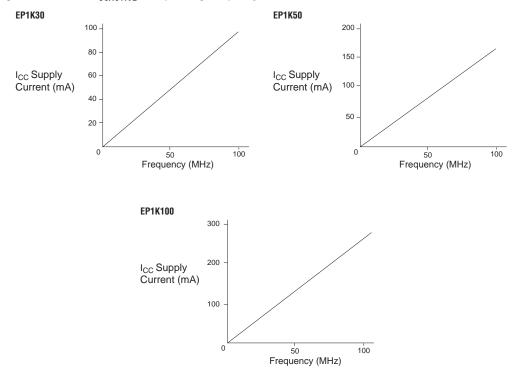


Figure 31. ACEX 1K I_{CCACTIVE} vs. Operating Frequency

Configuration & Operation

The ACEX 1K architecture supports several configuration schemes. This section summarizes the device operating modes and available device configuration schemes.

Operating Modes

The ACEX 1K architecture uses SRAM configuration elements that require configuration data to be loaded every time the circuit powers up. The process of physically loading the SRAM data into the device is called *configuration*. Before configuration, as $V_{\rm CC}$ rises, the device initiates a Power-On Reset (POR). This POR event clears the device and prepares it for configuration. The ACEX 1K POR time does not exceed 50 μ s.



When configuring with a configuration device, refer to the relevant configuration device data sheet for POR timing information.

During initialization, which occurs immediately after configuration, the device resets registers, enables I/O pins, and begins to operate as a logic device. Before and during configuration, all I/O pins (except dedicated inputs, clock, or configuration pins) are pulled high by a weak pull-up resistor. Together, the configuration and initialization processes are called *command mode*; normal device operation is called *user mode*.

SRAM configuration elements allow ACEX 1K devices to be reconfigured in-circuit by loading new configuration data into the device. Real-time reconfiguration is performed by forcing the device into command mode with a device pin, loading different configuration data, re-initializing the device, and resuming user-mode operation. The entire reconfiguration process requires less than 40 ms and can be used to reconfigure an entire system dynamically. In-field upgrades can be performed by distributing new configuration files.

Configuration Schemes

The configuration data for an ACEX 1K device can be loaded with one of five configuration schemes (see Table 59), chosen on the basis of the target application. An EPC16, EPC2, EPC1, or EPC1441 configuration device, intelligent controller, or the JTAG port can be used to control the configuration of a ACEX 1K device, allowing automatic configuration on system power-up.

Multiple ACEX 1K devices can be configured in any of the five configuration schemes by connecting the configuration enable (nCE) and configuration enable output (nCEO) pins on each device. Additional APEX 20K, APEX 20KE, FLEX 10K, FLEX 10KA, FLEX 10KE, ACEX 1K, and FLEX 6000 devices can be configured in the same serial chain.

Table 59. Data Sources for ACEX 1K Configuration				
Configuration Scheme	Data Source			
Configuration device	EPC16, EPC2, EPC1, or EPC1441 configuration device			
Passive serial (PS)	BitBlaster or ByteBlasterMV download cables, or serial data source			
Passive parallel asynchronous (PPA)	Parallel data source			
Passive parallel synchronous (PPS)	Parallel data source			
JTAG	BitBlaster or ByteBlasterMV download cables, or microprocessor with a Jam STAPL File or JBC File			

Device Pin-Outs

See the Altera web site (http://www.altera.com) or the *Altera Documentation Library* for pin-out information.

Revision History

The information contained in the *ACEX 1K Programmable Logic Device Family Data Sheet* version 3.4 supersedes information published in previous versions.

The following changes were made to the *ACEX 1K Programmable Logic Device Family Data Sheet* version 3.4: added extended temperature support.



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